

EAST Search History

EAST Search History (Prior Art)

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	21361	324/207.2,207.21,249,251,252.ccls. 338/32R,32H.ccls. 438/3,14,17.ccls. 29/592,591.1,602.1,603.1,607.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/09/24 16:06
L2	696	L1 and spin near2 valve	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/09/24 16:06
L3	622	L2 and (substrate semiconductor)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/09/24 16:06
L4	609	L3 and layer	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/09/24 16:06
L5	595	L4 and (magnet\$2 near2 resist\$3 magneto \$1resist\$4 gmr tnr)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/09/24 16:06
L6	9847	spin near2 valve	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/09/24 16:06
L7	6191	L6 and (substrate semiconductor)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/09/24 16:06
L8	3458	L7 and (pinned near3 layer) and (free near3 layer)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/09/24 16:06
L9	3381	L8 and (magnet\$2 near2 resist\$3 magneto \$1resist\$4 gmr tnr)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/09/24 16:06

L10	21361	324/207.2,207.21,249,251,252.ccls. 338/32R,32H.ccls. 438/3,14,17.ccls. 29/592,591.1,602.1,603.1,607.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/09/24 16:06
L11	696	L10 and spin near2 valve	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/09/24 16:06
L12	622	L11 and (substrate semiconductor)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/09/24 16:06
L13	609	L12 and layer	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/09/24 16:06
L14	595	L13 and (magnet\$2 near2 resist\$3 magneto \$1resist\$4 gmr tnr)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/09/24 16:06
L15	9847	spin near2 valve	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/09/24 16:06
L16	6191	L15 and (substrate semiconductor)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/09/24 16:06
L17	3458	L16 and (pinned near3 layer) and (free near3 layer)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/09/24 16:06
L18	3381	L17 and (magnet\$2 near2 resist\$3 magneto \$1resist\$4 gmr tnr)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/09/24 16:06
L19	3043	L18 not L14	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/09/24 16:06

EAST Search History (Interference)

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